XN01117 (XN1117)

Silicon PNP epitaxial planer transistor

For switching/digital circuits

Features

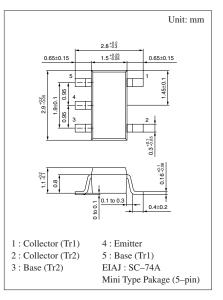
- Two elements incorporated into one package. (Emitter-coupled transistors with built-in resistor)
- Reduction of the mounting area and assembly cost by one half.

Basic Part Number of Element

• UNR1117(UN1117) \times 2 elements

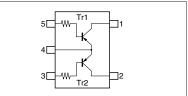
| Parameter | | Symbol | Ratings | Unit | | | |
|-------------------------|------------------------------|------------------|-------------|------|--|--|--|
| Rating of element | Collector to base voltage | V _{CBO} | -50 | V | | | |
| | Collector to emitter voltage | V _{CEO} | -50 | V | | | |
| | Collector current | I _C | -100 | mA | | | |
| Overall | Total power dissipation | P _T | 300 | mW | | | |
| | Junction temperature | Tj | 150 | °C | | | |
| | Storage temperature | T _{stg} | -55 to +150 | °C | | | |
| | | | | | | | |

Absolute Maximum Ratings (Ta=25°C)



Marking Symbol: OL

Internal Connection

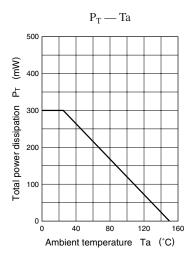


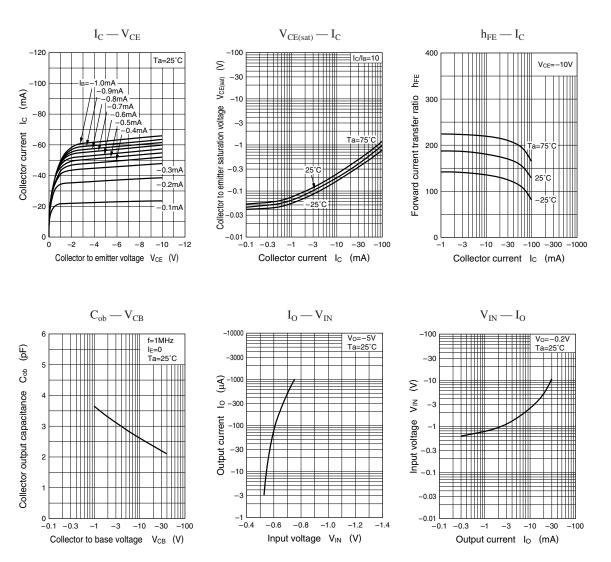
Electrical Characteristics (Ta=25°C)

| Parameter | Symbol | Conditions | min | typ | max | Unit |
|---|---------------------------------|---|------|------|--------|------|
| Collector to base voltage | V _{CBO} | $I_{\rm C} = -10 \mu A, I_{\rm E} = 0$ | -50 | | | V |
| Collector to emitter voltage | V _{CEO} | $I_{\rm C} = -2mA, I_{\rm B} = 0$ | -50 | | | V |
| Collector cutoff current | I _{CBO} | $V_{CB} = -50V, I_E = 0$ | | | - 0.1 | μΑ |
| | I _{CEO} | $V_{CE} = -50V, I_B = 0$ | | | - 0.5 | μΑ |
| Emitter cutoff current | I _{EBO} | $V_{EB} = -6V, I_C = 0$ | | | - 0.01 | mA |
| Forward current transfer ratio | h _{FE} | $V_{CE} = -10V, I_C = -5mA$ | 160 | | 460 | |
| Forward current transfer h_{FE} ratio | h _{FE} (small/large)*1 | $V_{CE} = -10V, I_C = -5mA$ | 0.5 | 0.99 | | |
| Collector to emitter saturation voltage | V _{CE(sat)} | $I_{\rm C} = -10 {\rm mA}, I_{\rm B} = -0.3 {\rm mA}$ | | | - 0.25 | V |
| Output voltage high level | V _{OH} | $V_{CC} = -5V, V_B = -0.5V, R_L = 1k\Omega$ | -4.9 | | | V |
| Output voltage low level | V _{OL} | $V_{CC} = -5V, V_B = -2.5V, R_L = 1k\Omega$ | | | - 0.2 | V |
| Transition frequency | f _T | $V_{CB} = -10V, I_E = 1mA, f = 200MHz$ | | 80 | | MHz |
| Input resistance | R ₁ | | -30% | 22 | +30% | kΩ |

*1 Ratio between 2 elements

Note.) The Part number in the Parenthesis shows conventional part number.





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